

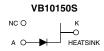
Vishay General Semiconductor

High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.59 \text{ V}$ at $I_F = 5.0 \text{ A}$



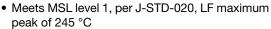




PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I _{F(AV)}	10 A			
V _{RRM}	150 V			
I _{FSM}	120 A			
V _F at I _F = 10 A	0.69 V			
T _J max.	150 °C			
Diode variations	Single die			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation





FREE

Material categorization:
For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VB10150S	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	150	V		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	10	А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	120	А		
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C		

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode (1)	I _F = 5.0 A	T _A = 25 °C	V _F	0.79	-	V	
	I _F = 10 A			1.05	1.20		
	$I_F = 5.0 \text{ A}$	T _A = 125 °C		0.59	-		
	I _F = 10 A			0.69	0.75		
Reverse current per diode ⁽²⁾	V _B = 100 V	T _A = 25 °C	I _R	1.3	-	μA	
	V _R = 100 V	T _A = 125 °C		1.2	-	mA	
	V _R = 150 V	T _A = 25 °C		-	150	μA	
	v _R = 150 v	T _A = 125 °C		3	15	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VB10150S	UNIT	
Typical thermal resistance	$R_{ heta JC}$	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VB10150S-M3/4W	1.37	4W	50/tube	Tube		
TO-263AB	VB10150S-M3/8W	1.37	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

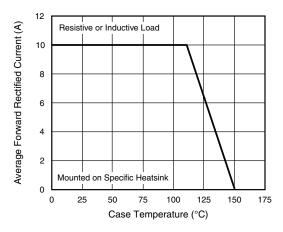


Fig. 1 - Maximum Forward Current Derating Curve

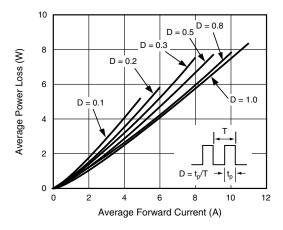


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

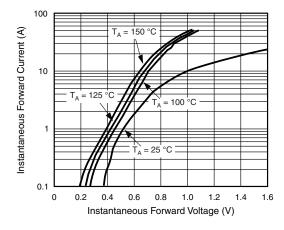


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

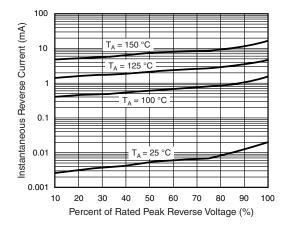


Fig. 4 - Typical Reverse Characteristics Per Diode



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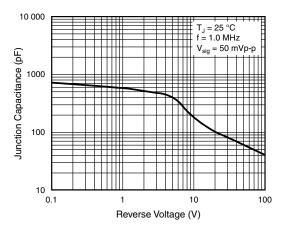


Fig. 5 - Typical Junction Capacitance Per Diode

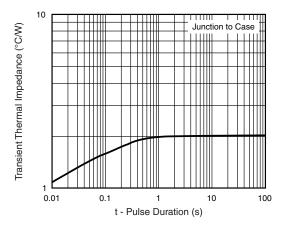
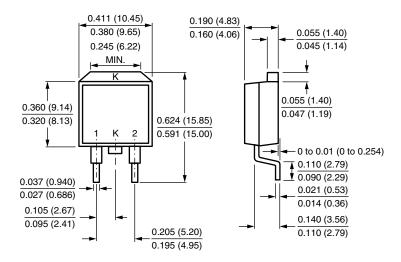


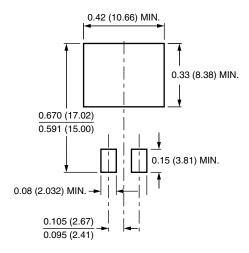
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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